

DRV3203E-Q1 Three-Phase Brushless Motor Driver

Not Recommended for New Designs

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified with the Following Results:
 - Device Temperature Grade 0: -40°C to 150°C
 - Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C2
- 3-Phase Pre-Drivers for N-Channel MOS Field-Effect Transistors (MOSFETs)
- Pulse-Width Modulation (PWM) Frequency up to 20 kHz
- Fault Diagnostics
- Charge Pump
- Phase Comparators
- Microcontroller (MCU) Reset Generator
- Serial Port I/F (SPI)
- Motor-Current Sense
- 3.3-V Regulator
- Low-Current Sleep Mode
- Operation VB Range From 5.3 to 26.5 V
- 48-Pin PHP

2 Applications

- Automotive Motor-Control Applications
 - Oil Pump
 - Fuel Pump
 - Water Pump

3 Description

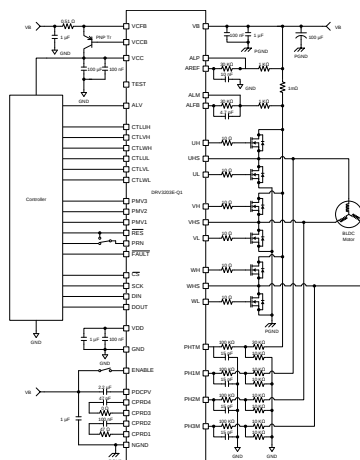
The DRV3203E-Q1 device is a field-effect transistor (FET) driver designed for three-phase motor control for applications such as an oil pump or a water pump. The device has three high-side pre-FET drivers and three low-side drivers which are under the control of an external MCU. A charge pump supplies the power for the high side, and there is no requirement for a bootstrap capacitor. For commutation, this integrated circuit (IC) sends a conditional motor signal and output to the MCU. Diagnostics provide undervoltage, overvoltage, overcurrent, overtemperature and power-bridge faults. One can measure the motor current using an integrated current-sense amplifier and comparator in a battery common-mode range, which allows the use of the motor current in a high-side current-sense application. External resistors set the gain. One can configure the pre-drivers and other internal settings through the SPI.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
DRV3203E-Q1	HTQFP (48)	7.00 mm × 7.00 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Typical Application Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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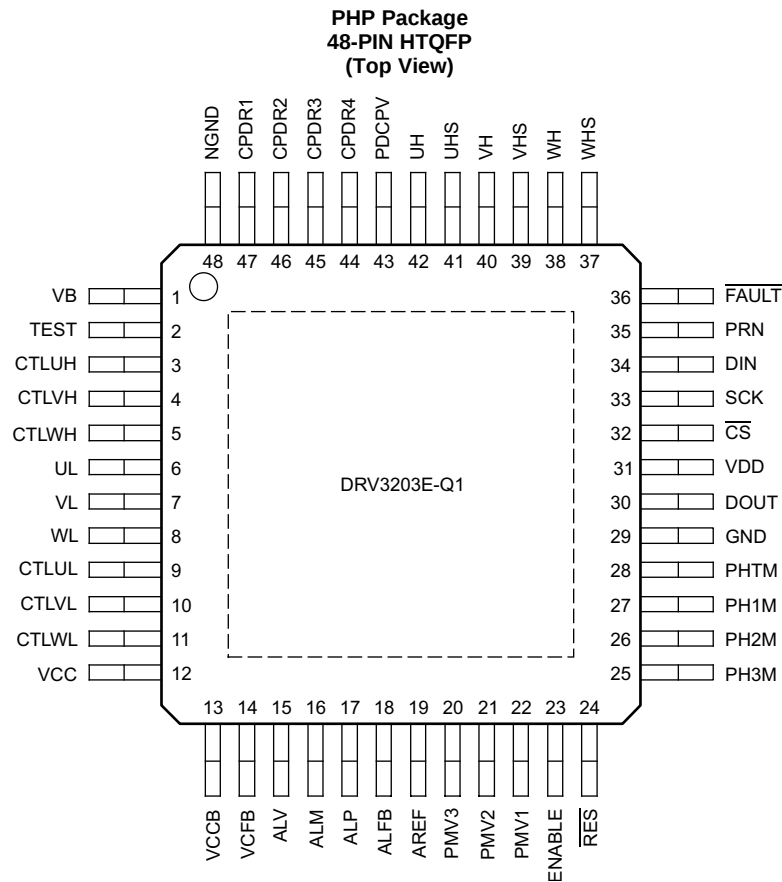
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (January 2014) to Revision B	Page
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Application and Implementation</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section	1

Changes from Original (November 2013) to Revision A	Page
• Changed symbol for the Data delay time, SCK to DOUT parameter in the <i>SPI ELECTRICAL CHARACTERISTICS</i> table from t_v to t_d	5
• Changed the delay time, SCK to DOUT image reference from Figure 23 to Figure 2 in the <i>SPI ELECTRICAL CHARACTERISTICS</i> table	5
• Changed the max value for the RONH_HP parameter from 310 to 300 in the <i>Pre-Driver Electrical Characteristics</i> table ...	7
• Deleted the 1 from the symbols for the time parameters (t_{on_h} , t_{off_h} , t_{h-on} , and t_{h-off}) for the high-side pre-driver in the <i>Pre-Driver Electrical Characteristics</i> table	7
• Changed the max for the VOL_L parameter from 55 to 60 in the <i>Pre-Driver Electrical Characteristics</i> table	7
• Changed the max for the RONL_L parameter from 5 to 6 in the <i>Pre-Driver Electrical Characteristics</i> table	7
• Changed the symbol for the turnoff time parameter for the low-side pre-driver from t_{off_h} to t_{off_l} in the <i>Pre-Driver Electrical Characteristics</i> table	7
• Changed conditions of Tset_TR2, Tset_TF2 and OVADth in the <i>Motor Current-Sense Electrical Characteristics</i> table	9
• Changed the value for the VCCUVHYS parameters in the <i>VCC and VDD Electrical Characteristics</i> table from 50, 100, and 200 to 33, 66, and 132	9
• Added ADTH to the bit 6:4 description in the FLTCFG register table	26
• Changed the description for writing a 0 to bit 2 in the FLTCFB register table from 2.3 to 2.2 V	26
• Changed the dead time description for bit 1:0 in the PDCFG register table from 2, 1.5, 1, and 0.5 to 2.1, 1.6, 1.1, and 0.6 (respectively). Also changed the actual deadtime from ± 0.2 to ± 0.1	30

5 Pin Configuration and Functions



Pin Functions

PIN		TYPE	MAXIMUM RATING	FUNCTION
NAME	NO.			
ALFB	18	O	–0.3 V to 40 V	Motor current-sense amplifier feedback
ALM	16	I	–0.3 V to 40 V	Motor current- sense amplifier negative input
ALP	17	I	–0.3 V to 40 V	Motor current- sense amplifier positive input
ALV	15	O	–0.3 V to 3.6 V	Motor current- sense amplifier output
AREF	19	O	–0.3 V to 40 V	Reference output of motor current- sense amplifier
CPDR1	47	O	–0.3 V to 40 V	Charge-pump output
CPDR2	46	O	–0.3 V to 40 V	Charge- pump output
CPDR3	45	O	–0.3 V to 40 V	Charge- pump output
CPDR4	44	O	–0.3 V to 40 V	Charge- pump output
$\overline{CS}$	32	I	–0.3 V to 3.6 V	SPI chip select
CTLUH	3	I	–0.3 V to 3.6 V	Pre-driver parallel input
CTLUL	9	I	–0.3 V to 3.6 V	Pre-driver parallel input
CTLVH	4	I	–0.3 V to 3.6 V	Pre-driver parallel input
CTLVL	10	I	–0.3 V to 3.6 V	Pre-driver parallel input
CTLWH	5	I	–0.3 V to 3.6 V	Pre-driver parallel input
CTLWL	11	I	–0.3 V to 3.6 V	Pre-driver parallel input
DIN	34	I	–0.3 V to 3.6 V	SPI data input
DOUT	30	O	–0.3 V to 3.6 V	SPI data output

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Pin Functions (continued)

PIN		TYPE	MAXIMUM RATING	FUNCTION
NAME	NO.			
ENABLE	23	I	–0.3 V to 40 V	Enable input
$\overline{\text{FAULT}}$	36	O	–0.3 V to 3.6 V	Diagnosis output
GND	29	I	–0.3 V to 0.3 V	GND
NGND	48	I	–0.3 V to 0.3 V	Power GND
PDCPV	43	O	–0.3 V to 40 V	Charge pump output
PH1M	27	I	–1 V to 40 V	Phase comparator input
PH2M	26	I	–1 V to 40 V	Phase comparator input
PH3M	25	I	–1 V to 40 V	Phase comparator input
PHTM	28	I	–1 V to 40 V	Phase comparator reference input
PMV1	22	O	–0.3 V to 3.6 V	Phase comparator output
PMV2	21	O	–0.3 V to 3.6 V	Phase comparator output
PMV3	20	O	–0.3 V to 3.6 V	Phase comparator output
PRN	35	I	–0.3 V to 3.6 V	Watchdog timer-pulse input
$\overline{\text{RES}}$	24	O	–0.3 V to 3.6 V	MCU reset output
SCK	33	I	–0.3 V to 3.6 V	SPI clock
TEST	2	I	–0.3 V to 20 V	TEST input
UH	42	O	–5 V to 40 V	Pre-driver output
UHS	41	O	–5 V to 40 V	Pre-driver reference
UL	6	O	–0.3 V to 20 V	Pre-driver output
VB	1	I	–0.3 V to 40 V	VB input
VCC	12	I	–0.3 V to 3.6 V	VCC supply input
VCCB	13	O	–0.3 V to 40 V	VCC regulator base driver of PNP external transistor
VCFB	14	I	–0.3 V to 40 V	VCC regulator current-sense input
VDD	31	O	–0.3 V to 3.6 V	VDD supply output
VH	40	O	–5 V to 40 V	Pre-driver output
VHS	39	O	–5 V to 40 V	Pre-driver reference
VL	7	O	–0.3 V to 20 V	Pre-driver output
WH	38	O	–5 V to 40 V	Pre-driver output
WHS	37	O	–5 V to 40 V	Pre-driver reference
WL	8	O	–0.3 V to 20 V	Pre-driver output

6 Specifications**6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
T_A Operating temperature range	–40	150	°C
T_J Junction temperature	–40	175	°C
T_{stg} Storage temperature	–55	175	°C

6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
	Charged-device model (CDM), per AEC Q100-011	±500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Thermal Information

THERMAL METRIC		DRV3203E-Q1	UNIT
		PHP (HTQFP)	
		48 PINS	
θ_{JA}	Junction-to-ambient thermal resistance	26.1	°C/W
θ_{JCTop}	Junction-to-case (top) thermal resistance	11.5	°C/W
θ_{JB}	Junction-to-board thermal resistance	7.2	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	7.1	°C/W
θ_{JCbott}	Junction-to-case (bottom) thermal resistance	0.4	°C/W

6.4 Electrical Characteristics

$V_B = 12\text{ V}$, $T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
WATCHDOG						
VSTN ⁽¹⁾	Function start VCC voltage $\overline{\text{RES}}$	See Figure 1	-	0.8	1.3	V
t _{ON} ⁽¹⁾	Power-on time $\overline{\text{RES}}$		2.5	3	3.5	ms
t _{OFF} ⁽¹⁾	Clock-off reset time $\overline{\text{RES}}$		64	80	96	ms
t _{RL} ⁽¹⁾	Reset-pulse low time $\overline{\text{RES}}$		16	20	24	ms
t _{RH} ⁽¹⁾	Reset-pulse high time $\overline{\text{RES}}$		64	80	96	ms
t _{RES} ⁽¹⁾	Reset delay time $\overline{\text{RES}}$		30	71.5	90	μs
P _{wth} ⁽¹⁾	Pulse duration PRN		2	-	-	μs
SPI						
f _{op}	SPI clock frequency		-	4	MHz	
t _{lead} ⁽¹⁾	Enable lead time		200	-	-	ns
t _{wait} ⁽¹⁾	Wait time between two successive communications		5	-	-	μs
t _{lag} ⁽¹⁾	Enable lag time		100	-	-	ns
t _{pw} ⁽¹⁾	SCLK pulse duration		100	-	-	ns
t _{su} ⁽¹⁾	Data setup time		100	-	-	ns
t _h ⁽¹⁾	Data hold time		100	-	-	ns
t _{dis} ⁽¹⁾	Data-output disable time		-	-	200	ns
t _{en} ⁽¹⁾	Data-output enable time		-	-	100	ns
t _d ⁽¹⁾	Data delay time, SCK to DOUT	C _L = 50 pF, see Figure 2.	0	-	100	ns
CHARGE PUMP						
Vchv1_0	Output voltage, PDCPV	VB = 5.3 V, load = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 μF, R1 = R2 = 0 Ω	VB + 7	VB + 8	-	V
Vchv1_1	Output voltage, PDCPV	VB = 5.3 V, load = 5 mA, C1 = C2 = 47 nF, CCP = 2.2 μF, R1 = R2 = 0 Ω	VB + 5.5	VB + 6.5	-	V
Vchv1_2	Output voltage, PDCPV	VB = 5.3 V, load = 8 mA, C1 = C2 = 47 nF, CCP = 2.2 μF, R1 = R2 = 0 Ω	VB + 4.5	VB + 5.5	-	V

(1) Specified by design.

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VB = 12 V, TA = –40°C to +150°C (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Vchv2_0	Output voltage, PDCPV	VB = 12 V, load = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 10	VB + 12	VB + 14	V
Vchv2_1	Output voltage, PDCPV	VB = 12 V, load = 11 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 9.5	VB + 11.5	VB + 13.5	V
Vchv2_2	Output voltage, PDCPV	VB = 12 V, load = 18 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 9	VB + 11	VB + 13	V
Vchv3_0	Output voltage, PDCPV	VB = 18 V, load = 0 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 10	VB + 12	VB + 14	V
Vchv3_1	Output voltage, PDCPV	VB = 18 V, load = 13 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 10	VB + 12	VB + 14	V
Vchv3_2	Output voltage, PDCPV	VB = 18 V, load = 22 mA, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω	VB + 10	VB + 12	VB + 14	V
VchvOV	Overvoltage detection threshold		35	37.5	40	V
VchvUV	Undervoltage detection threshold		VB + 4	VB + 4.5	VB + 5	V
t _{chv} ⁽¹⁾	Rise time	VB = 5.3 V, C1 = C2 = 47 nF, CCP = 2.2 µF, R1 = R2 = 0 Ω, Vchv, UV released		1	2	ms
Ron	On-resistance, S1-S4	See Figure 10		8		Ω

Electrical Characteristics (continued)

$V_B = 12\text{ V}$, $T_A = -40^\circ\text{C}$ to $+150^\circ\text{C}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
HIGH-SIDE PRE-DRIVER						
VOH_H	Output voltage, turnon side	Isink = 10 mA, PDCPV - xH		1.35	2.7	V
VOL_H	Output voltage, turnoff side	Isource = 10 mA, xH - xHS		25	50	mV
RONH_HP	On-resistance, turnon side (Pch)	$U(V/W)H = PDCPV - 1\text{ V}$		135	300	Ω
RONH_HN	On-resistance, turnon side (Nch)	$U(V/W)H = PDCPV - 2.5\text{ V}$		4	8	Ω
RONL_H	On-resistance turnoff side			2.5	5	Ω
$t_{on_h}^{(1)}$	Turnon time	$C_L = 12\text{ nF}$, $R_L = 0\ \Omega$ from 20% to 80%	50	-	200	ns
$t_{off_h}^{(1)}$	Turnoff time	$C_L = 12\text{ nF}$, $R_L = 0\ \Omega$ from 80% to 20%	50	-	200	ns
$t_{h_ondly}^{(1)}$	Output delay time	$C_L = 12\text{ nF}$, $R_L = 0\ \Omega$ to 20%, no dead time	-	200	-	ns
$t_{h_offdly}^{(1)}$	Output delay time	$C_L = 12\text{ nF}$, $R_L = 0\ \Omega$ to 80%, no dead time	-	200	-	ns
VGS_hs	Gate-source high -side voltage difference	xH-xHS	-0.3		18	V
LOW-SIDE PRE-DRIVER						
VOH_L1	Output voltage, turnon side	$V_B = 12\text{ V}$, Isink = 10 mA, xL -NGND	10	12	14	V
VOH_L2	Output voltage, turnon side	$V_B = 5.3\text{ V}$, Isink = 10 mA, xL - NGND	5.5	7.5	10	V
VOL_L	Output voltage, turnoff side	Isource = 10 mA, xL - NGND	-	25	60	mV
RONH_L	On-resistance, turnon side		-	6	12	Ω
RONL_L	On-resistance, turnoff side			2.5	6	Ω
$t_{on_l}^{(1)}$	Turnon time	$C_L = 18\text{ nF}$, $R_L = 0\ \Omega$, from 20% to 80% of 12 V, from 20% to 80% of 6 V ($V_B = 5.3\text{ V}$)	50	-	200	ns
$t_{off_l}^{(1)}$	Turnoff time	$C_L = 18\text{ nF}$, $R_L = 0\ \Omega$, from 80% to 20% of 12 V, from 80% to 20% of 6 V ($V_B = 5.3\text{ V}$)	50	-	200	ns
$t_{l_ondly}^{(1)}$	Output delay time	$C_L = 18\text{ nF}$, $R_L = 0\ \Omega$, to 20% of 12 V, to 20% of $V_{OH} = 6\text{ V}$ ($V_B = 5.3\text{ V}$), no dead time	-	200	-	ns
$t_{l_offdly}^{(1)}$	Output delay time	$C_L = 18\text{ nF}$, $R_L = 0\ \Omega$, to 80% of 12 V, to 80% of $V_{OH} = 6\text{ V}$ ($V_B = 5.3\text{ V}$), no dead time	-	200	-	ns
$t_{diff1}^{(1)}$	Differential time1	(Th-on) - (Tl-off), no dead time, See Figure 3	-200	0	200	ns

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Electrical Characteristics (continued)

VB = 12 V, TA = –40°C to +150°C (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{diff2}^{(1)}$	Differential time2	(TI-on) - (TI-off), no dead time, See Figure 3	–200	0	200	ns
$t_{dead}^{(1)}$	Dead time	OSC1 = 10 MHz SPI register PDCFG.DEADT	2 1.5 1 0.5		2.2 1.7 1.2 0.7	μs
PHASE COMPARTOR						
V _{IOfs}	Input offset voltage		–15	-	15	mV
V _{Im1}	Input voltage range, PHTM	VB = 6 V – 26.5 V	1.3	-	4.5	V
V _{Im2}	Input voltage range, PHTM	VB = 5.3 V	1.3	-	4.2	V
V _{Ip}	Input voltage range, PHxM		–1	-	VB	V
V _{hys}	Threshold hysteresis voltage	SPI register SPARE. SEL_COMP_HYS	-	0	-	mV
12.5	25	50				
25	50	100				
50	100	200				
V _{OH}	Output high voltage	Isink = 2.5 mA	0.9 × VCC	-	-	V
V _{OL}	Output low voltage	Isource = 2.5 mA	-	-	0.1 × VCC	V
$t_{res_tr}^{(1)}$	Response time, rising	C _L = 100 pF	-	0.7	1.5	μs
$t_{res_tf}^{(1)}$	Response time, falling	C _L = 100 pF	-	0.7	1.5	μs
MOTOR CURRENT SENSE						
V _{Ofs}	Input offset voltage		–5		5	mV
V _{O_0}	Output voltage, ALV	Imotor = 0 A, SPI register CSCFG. CSOFFSET	-	0.5 1 1.5	-	V
V _{Line}	Linearity, ALV	Rshunt = 1 mΩ, R11 = R12 = 1 kΩ, R21 = R22 = 30 kΩ	29.4	30	30.6	mV/A
V _{Gain}	Gain		10	30	-	V/V
Tset_TR1 ⁽¹⁾	Settling time (rise), ALV ±1%	Rshunt = 1 mΩ, V _{Gain} = 30, C _L = 100 pF, Imotor = 0 A → 30 A, (ALV: 1 V → 1.9 V, AREF = 1 V)	-	1	2.5	μs
Tset_TR2 ⁽¹⁾	Settling time(rise), ALV ±1%	Rshunt = 1 mΩ, V _{Gain} = 30, C _L = 100 pF, Imotor = 0 A → 60 A, (ALV: 1 V → 2.8 V, AREF = 1 V)	-	1	2.5	μs
Tset_TF1 ⁽¹⁾	Settling time(fall), ALV ±1%	Rshunt = 1 mΩ, V _{Gain} = 30, C _L = 100 pF, Imotor = 30 A → 0, (ALV: 1.9 V → 1 V, AREF = 1 V)	-	1	2.5	μs

Electrical Characteristics (continued)

VB = 12 V, TA = –40°C to +150°C (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Tset_TF2 ⁽¹⁾	Settling time(fall), ALV ±1%	Rshunt = 1 mΩ, VGain = 30, CL = 100 pF, Imotor = 60 A → 0, (ALV: 2.8 V → 1 V, AREF = 1 V)	-	1	2.5	μs
OVADth	Overcurrent threshold	Rshunt = 1 mΩ, VGain = 30, AREF = 1 V, ADTH = 1.98 V, SPI register FLTCFG. MTOCTH, OVADth = (2 × ADTH -- AREF) / (Rshunt × VGain)	89.1	99	108.9	A
TDEL_OVAD ⁽¹⁾	Propagation delay (rise or fall)		-	-	1.5	μs
tfiltMTOC	filtering time	OSC1 = 9 MHz-11 MHz	0.8	1	1.2	μs
VCC						
VCC1	Output Voltage		3.23	3.3	3.37	V
IBVCC	Base Current		2			mA
hfePNP	DC current gain of external PNP		100	-	-	
VLRVCC	Load regulation	ILVCC = 5 mA to 200 mA	-20	-	20	mV
CVCC	External Capacitance		22		100	μF
RVCC	ESR of external Capacitor				300	mΩ
VCCUV	Under voltage detection threshold	SPI register FLTCFG. VCCUVTH	2 2.2	2.2 2.4	2.4 2.6	V
VCCUVHYS	Under voltage detection threshold hysteresis		33	66	132	mV
VCCOV	Overvoltage detection threshold		3.5	3.8	4.1	V
VCCOC	Current Limit	Rsns = 0.51 Ω, 0.2 V = Rsns × VCCOC	300	400	550	mA
Tvcc1 ⁽¹⁾	Rise Time	VCC > VCCUV, CVCC = 22 μF			0.5	ms
Tvcc2 ⁽¹⁾	Rise Time	VCC > VCCUV, CVCC = 100 μF			1.5	ms
VDD						
VDD	Output Voltage		3	3.3	3.6	V
CVDD	Load Capacitance			1		μF
VDDUV	Under voltage detection threshold		2.1	2.3	2.5	V
VDDOV	Overvoltage detection threshold		4	4.3	4.6	V
Tvdd ⁽¹⁾	Rise Time	VDD > VDDUV, CVDD = 1 μF			100	μs
VB MONITOR						
VBOV	VB overvoltage detection threshold level		26.5	27.5	28.5	V
VBUV	VB Undervoltage detection threshold level	SPI register FLTCFG. VBUVTH	3.65 4.15 4.65 5.15	4 4.5 5 5.5	4.35 4.85 5.35 5.85	V
THERMAL SHUT DOWN						
TSD ⁽¹⁾	Thermal shut down threshold level		155	175	195	°C
TSDhys ⁽¹⁾	Thermal shut down hysteresis		5	10	15	°C

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Electrical Characteristics (continued)VB = 12 V, T_A = –40°C to +150°C (unless otherwise specified)

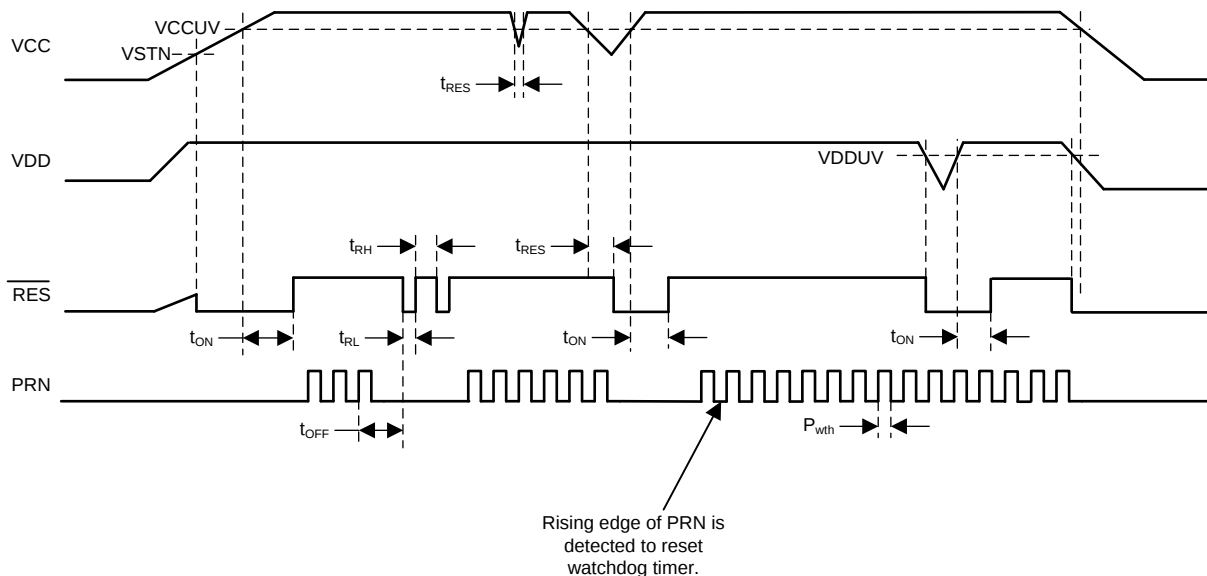
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
OSCILLATOR						
OSC1	OSC1 frequency		9	10	11	MHz
OSC2	OSC2 frequency			10		MHz
INPUT BUFFER1						
V _{IH}	Input threshold logic high		0.7 × VCC			V
V _{IL}	Input threshold logic low			0.3 × VCC		V
R _u or R _d	Input pullup or pulldown resistance		50	100	150	kΩ
OUTPUT BUFFER1(2)						
V _{OH}	Output level logic high	I _{sink} = 1 mA	0.9 × VCC			V
V _{OL}	Output level logic low	I _{source} = 1 mA		0.1 × VCC		V
OUTPUT BUFFER3						
R _{RES}	Pull up Resistor		2	3	4	kΩ
V _{OL}	Output level logic low	I _{source} = 2 mA		0.1 × VCC		V

6.5 Supply Voltage and CurrentVB = 12 V, T_A = –40°C to +150°C (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
SUPPLY INPUT						
VB1 ⁽¹⁾	VB supply voltage (motor operation)	Full device functionality	5.3	12	18	V
VB2 ⁽¹⁾	VB supply voltage (MCU operation)	Full device functionality	4.5	12	18	V
VB3 ⁽²⁾	VB supply voltage		18	-	26.5	V
I _{vb}	VB operating current	ENABLE = High, no PWM	-	18	27	mA
I _{vbq}	VB quiescent current	ENABLE = Low	-	50	100	μA

(1) Performance of supply voltage 5.3 to 18 V is according to the ACE-Q100 (Grade 0) standard.

(2) Specified by design.

NOTE: VCC undervoltage condition sets $\overline{\text{RES}}$ = Low.**Figure 1. Watchdog Timing Chart**

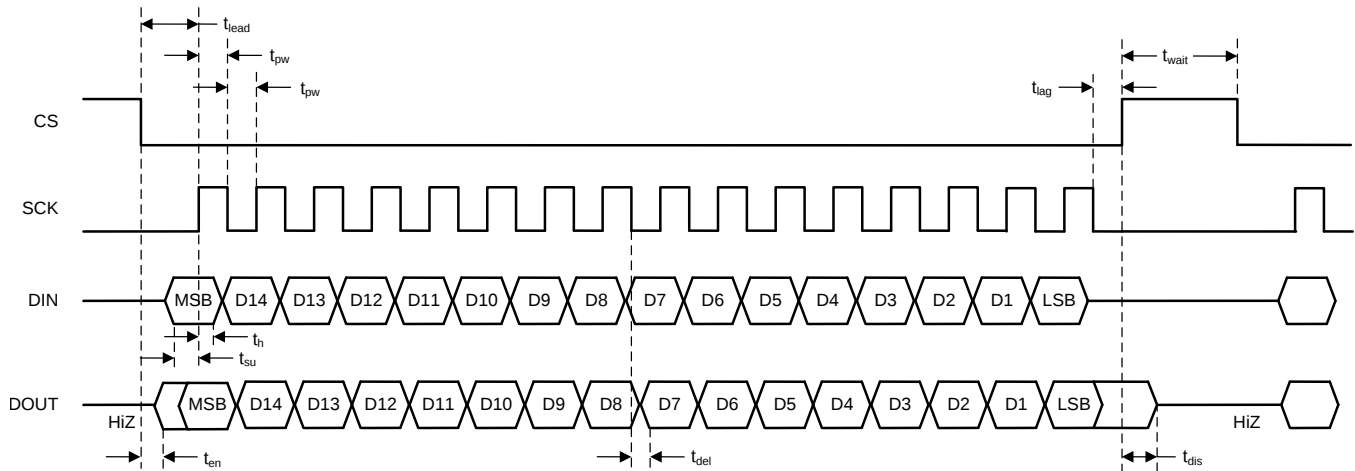
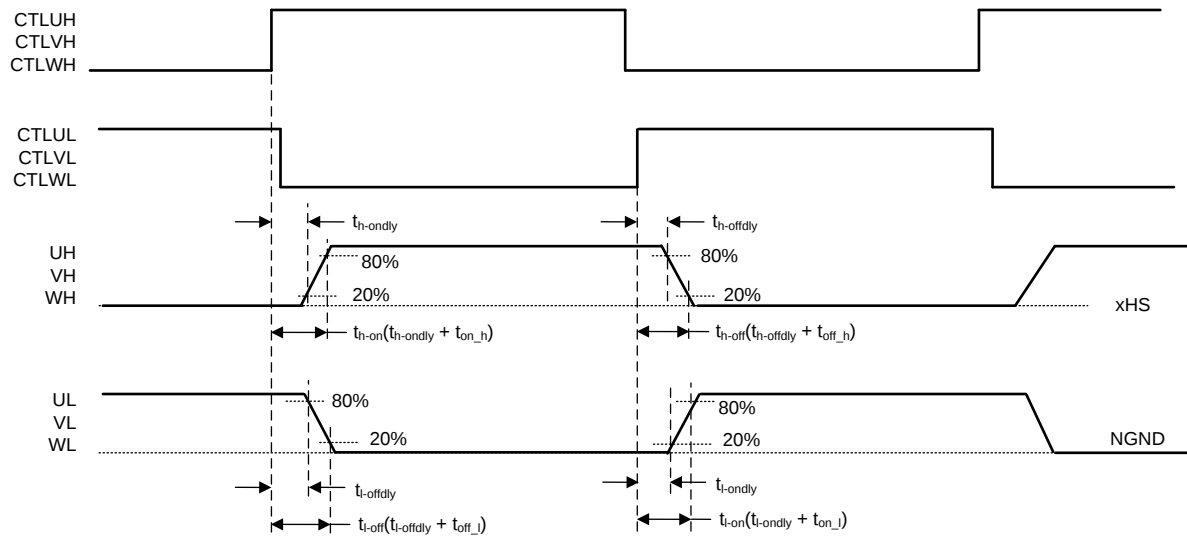


Figure 2. SPI Timing Diagram



NOTE: This diagram excludes dead time to explain the timing parameters of the pre-driver.

Figure 3. Delay Time From Input to Output

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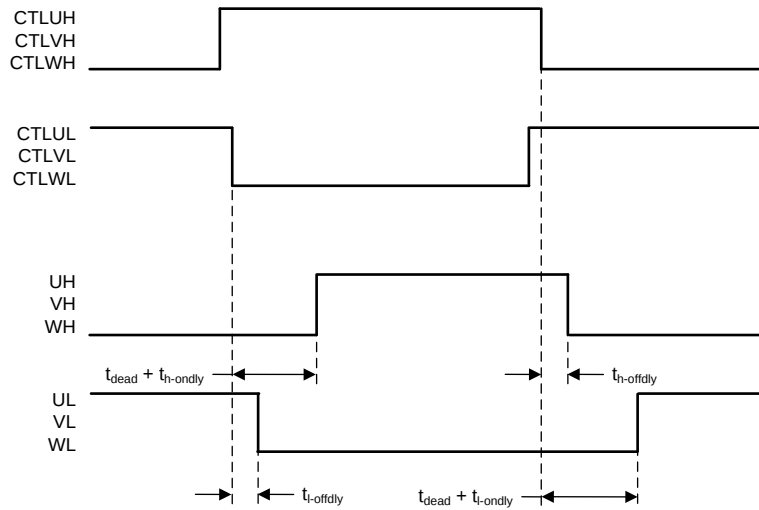


Figure 4. Dead Time

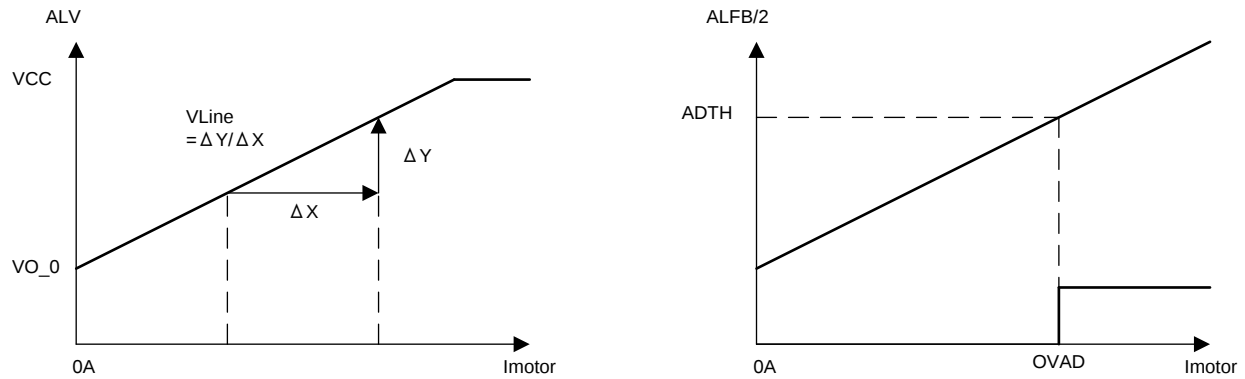
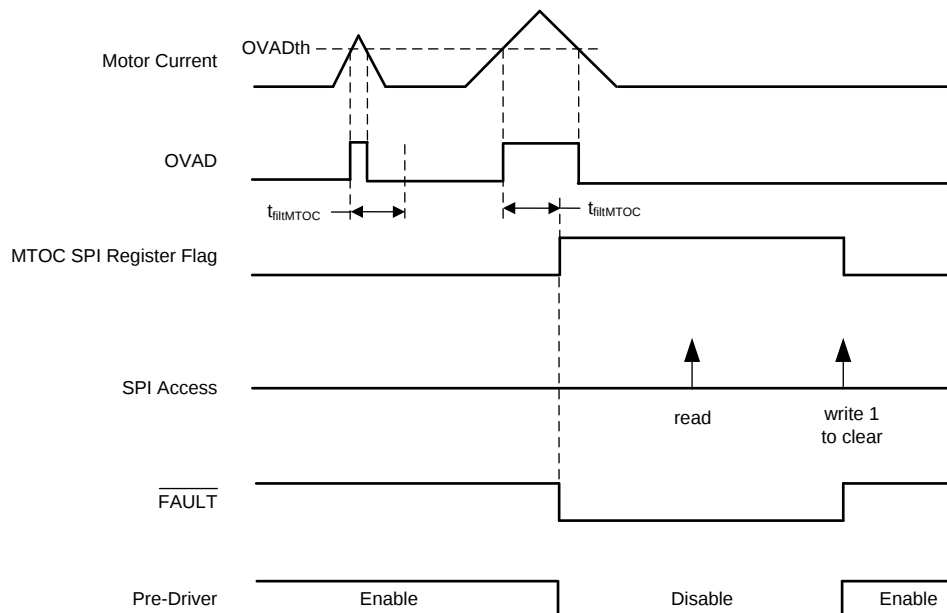


Figure 5. Motor Current Sense and Overcurrent



- (1) MCU must set the FLTCFG.FLGLATCH_EN bit to 1 to get the latch-type operation shown in this figure.
- (2) When MTOC condition is detected, $\overline{FAULT}$ is asserted to low if FE_MTOC bit is 1.
- (3) When MTOC condition is detected, Pre Driver is disabled if SE_MTOC is 1.

Figure 6. Motor Overcurrent Event

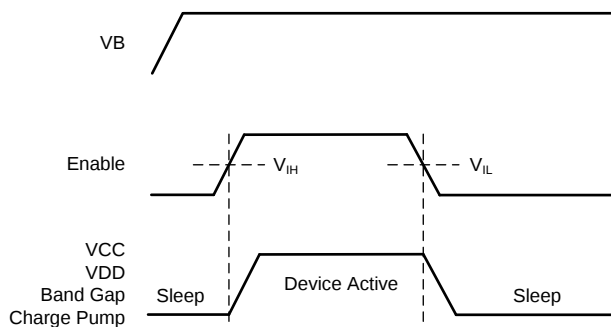


Figure 7. I/O ENABLE Timing Chart

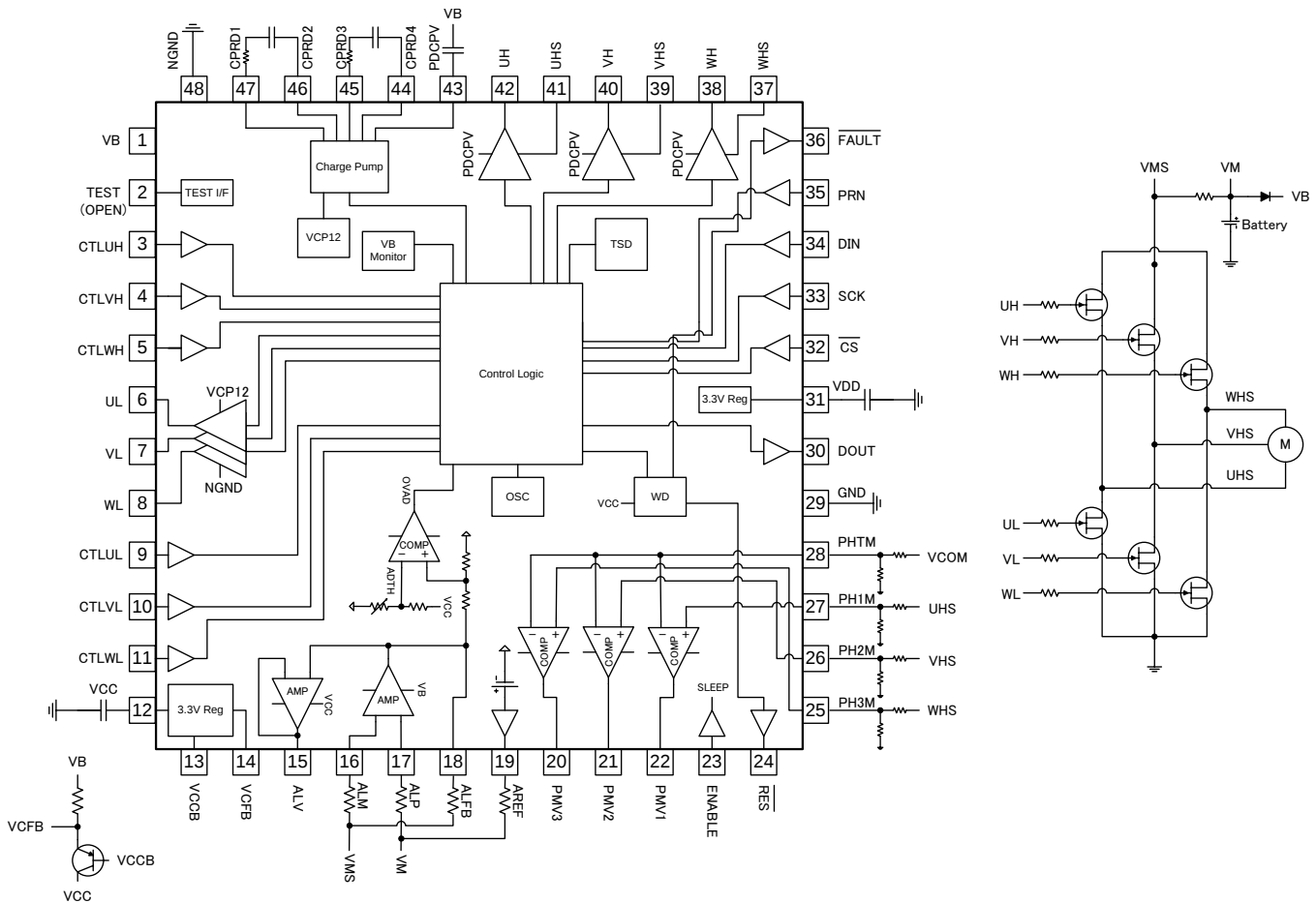
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7 Detailed Description

7.1 Functional Block Diagram



7.2 Feature Description

7.2.1 Watchdog

A watchdog monitors the PRN signal and VCC supply level and generates a reset to the MCU through the $\overline{\text{RES}}$ pin if the status of PRN is not normal or VCC is lower than the specified threshold level. Detection of a special pattern on the PRN input during power up can disable the watchdog.

Feature Description (continued)

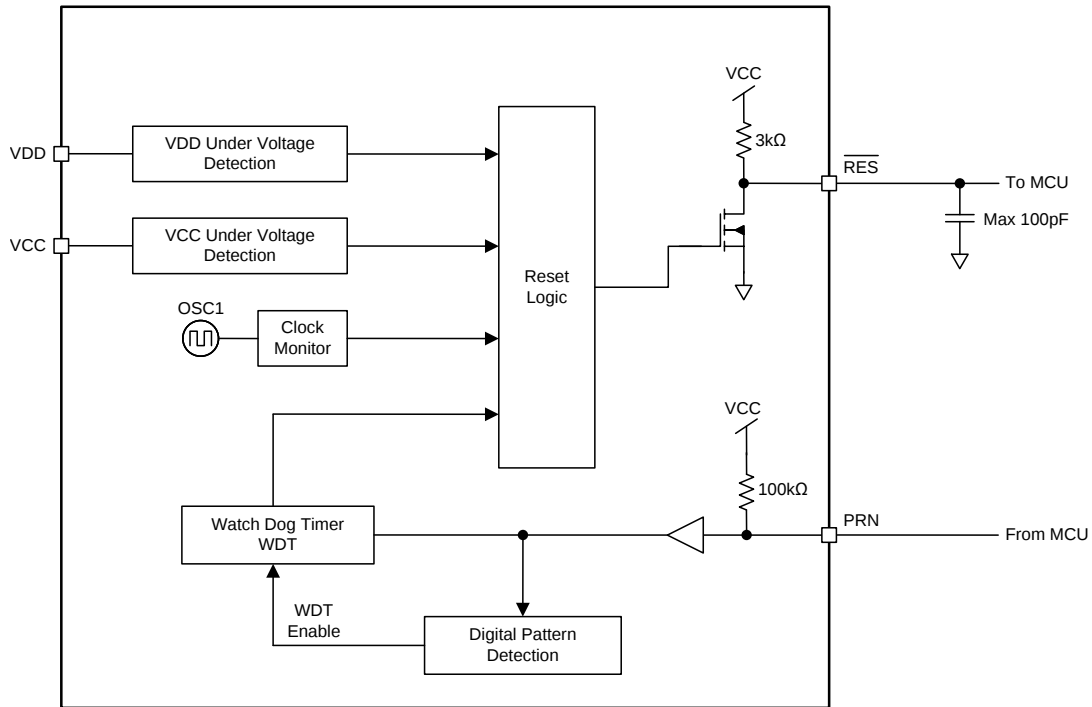


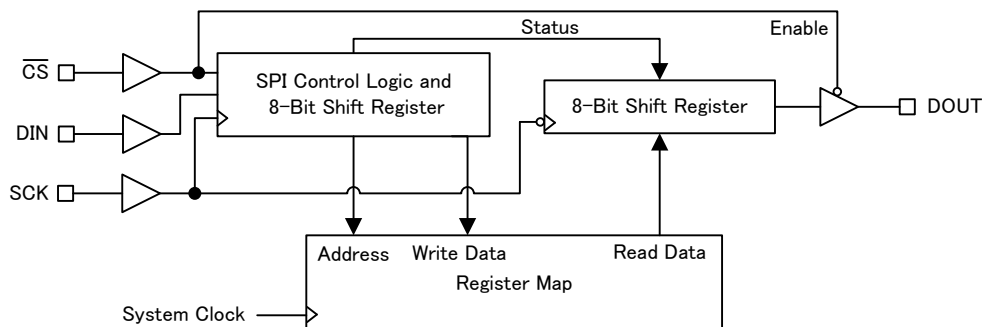
Figure 8. Watchdog Block Diagram

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www.ti.com**Feature Description (continued)****7.2.2 Serial Port I/F**

Setting device configuration and reading out diagnostic information is via SPI. SPI operates in slave mode. SPI uses four signals according to the timing chart of [Figure 2](#).

**Figure 9. Block Diagram of SPI****7.2.2.1 $\overline{CS}$ - Chip Select**

The MCU uses $\overline{CS}$ to select the IC. $\overline{CS}$ is normally high, and communication is possible only when it is forced low. When $\overline{CS}$ falls, communication between the IC and the MCU starts. The transmitted data are latched and the DOUT output pin leaves high impedance. When $\overline{CS}$ rises, communication stops. The DOUT output pin goes into high impedance. The next falling edge starts another communication. There is a minimum waiting time between the two communications (t_{wait}). The pin has an internal pullup.

7.2.2.2 SCK - Synchronization Serial Clock

The MCU uses SCK to synchronize communication. SCK is normally low, and the valid clock-pulse number is 16. At each falling edge, the MCU writes a new bit on the DIN input, and this IC writes a new bit on the DOUT output pin. At each rising edge, this IC reads the new bit on DIN, and the MCU reads the new bit on DOUT. The maximum clock frequency is 4 MHz. The pin has an internal pulldown.

7.2.2.3 DIN - Serial Input Data

DIN receives 16-bit data. The order of received bits is from the MSB (first) to the LSB (last). The pin has an internal pulldown. Update of the internal register with the received bits occurs only if the number of clock pulses is 16 while $\overline{CS}$ is low.

7.2.2.4 DOUT - Serial Output Data

DOUT transmits 16-bit data. It is a three-state output, and it is in the high-impedance state when $\overline{CS}$ is high. The order of serial data-bit transmission is from the MSB (first) to the LSB (last).

Feature Description (continued)

7.2.3 Charge Pump

The charge-pump block generates a supply for the high-side and low-side pre-drivers to maintain the gate voltage on the external FETs. Use of an external storage capacitor (CCP) and bucket capacitors (C1, C2) supports pre-driver slope and switching-frequency requirements. R1 and R2 reduce switching current if required. The charge pump has voltage-supervisor functions such as over- and undervoltage, and selectable stop conditions for pre-drivers.

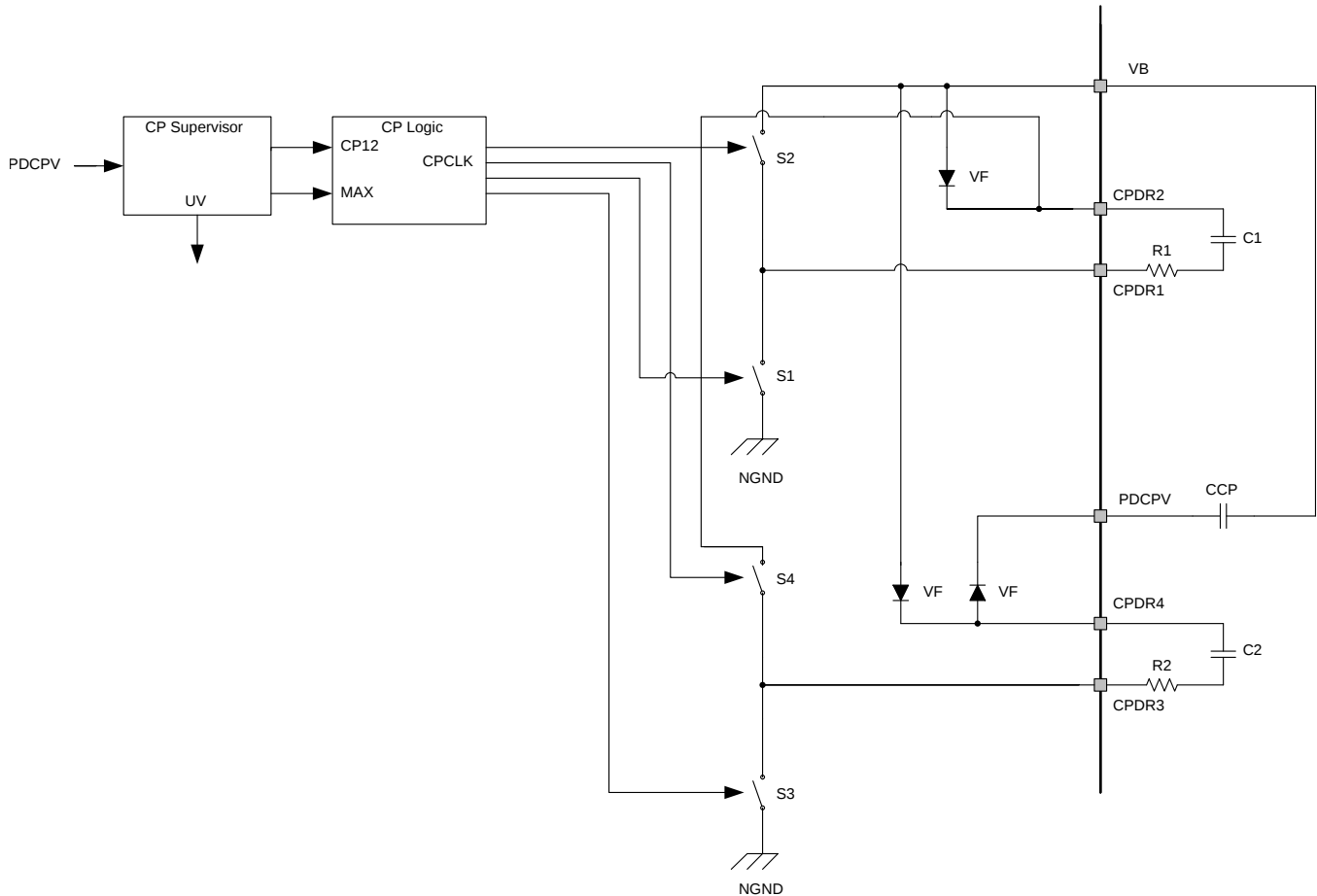


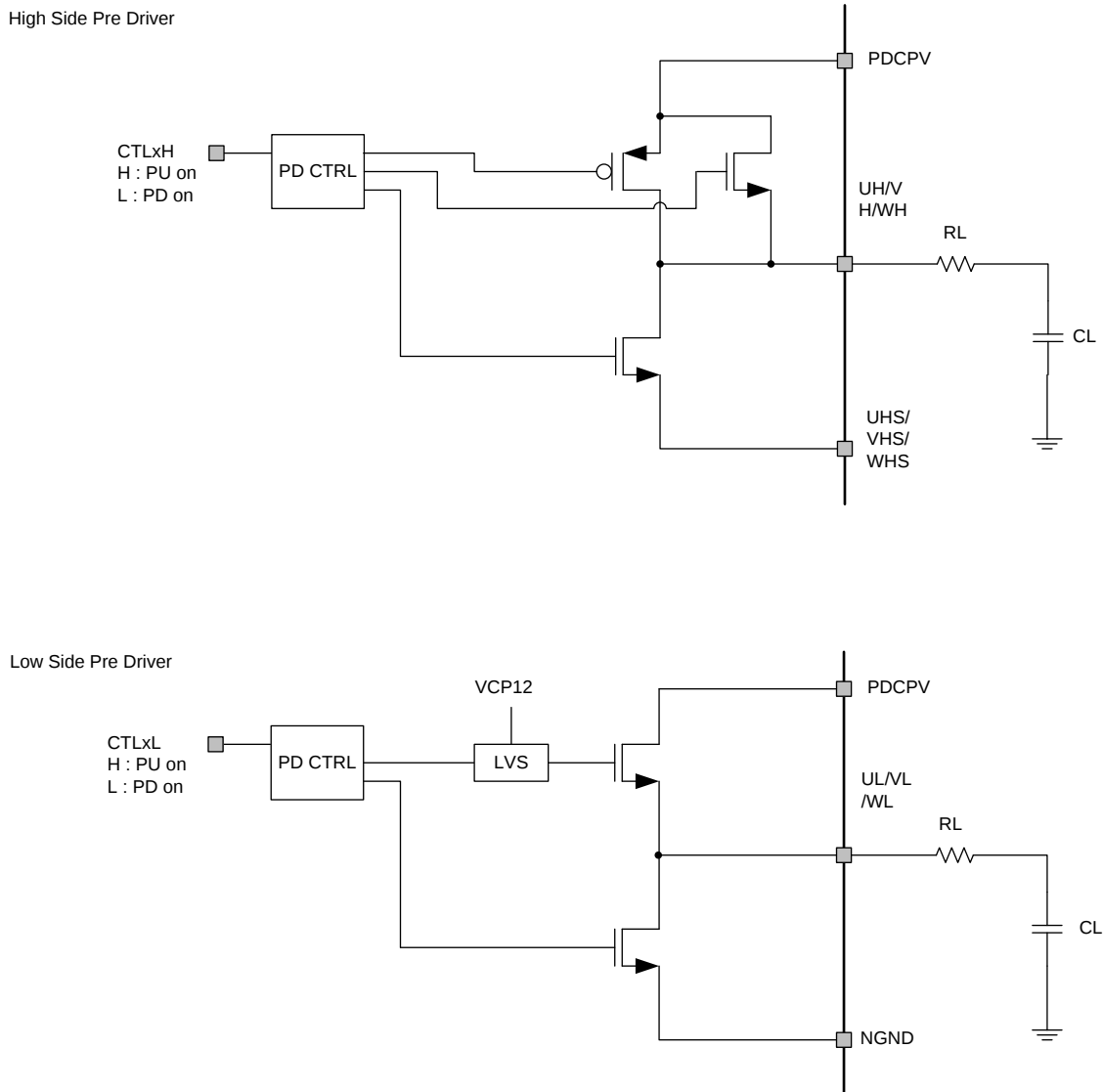
Figure 10. Charge-Pump Block Diagram

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www.ti.com**Feature Description (continued)****7.2.4 Pre-Driver**

The pre-driver block provides three high-side pre-drivers and three low-side pre-drivers to drive external N-channel MOSFETs. The turnon side of the high-side pre-drivers supplies the large N-channel transistor current for quick charge, and PMOS supports output voltages up to PDCPV. The turnoff side of the high-side pre-drivers supplies the large N-channel transistor current for quick discharge. The low-side pre-drivers supply the large N-channel transistor current for charge and discharge. VCP12 (created by a charge pump) controls the output voltage of the low-side pre-driver to output less than 18 V. The pre-driver has a stop condition in some fault conditions ([Fault Detection](#)) and SPI set ([Serial Port I/F](#)).

**Figure 11. Pre-Driver Block Diagram**

Feature Description (continued)

7.2.5 Phase Comparator

The three-channel comparator module monitors the external FETs by detecting the drain-source voltage across the high-side and low-side FETs. PHTM is the threshold level of the comparators usable for sensorless communication. [Figure 12](#) shows an example of the threshold level.

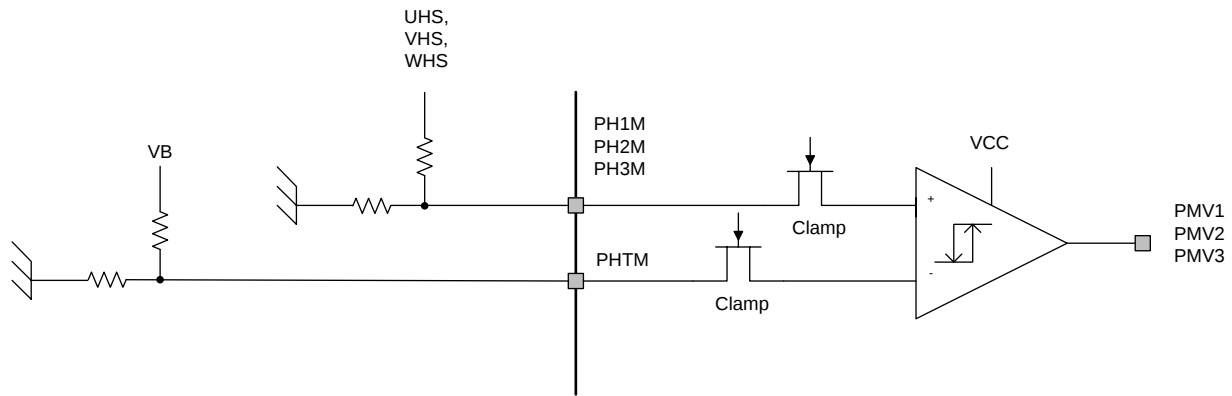


Figure 12. Phase Comparator Block Diagram

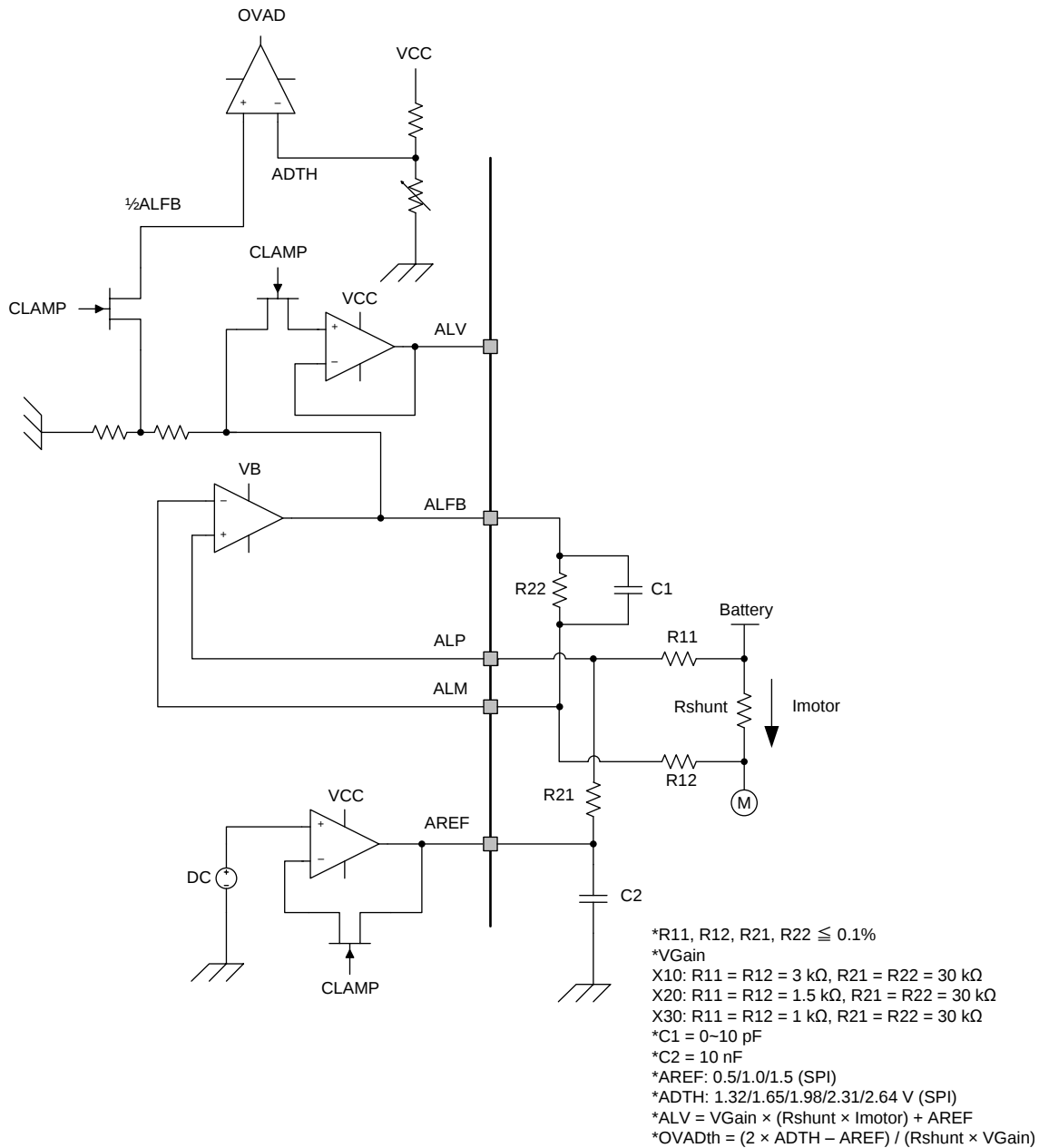
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Feature Description (continued)**7.2.6 Motor-Current Sense**

The operational amplifier operates with an external resistor network for higher flexibility to adjust the current measurement to application requirements. The first-stage amplifier operates with the external resistor and the output voltage up to VB at ALFB. External resistors adjust the amplifier gain by 10 to 30 times. The second-stage amplifier is buffered to MCU at ALV. The current sense has a comparator for motor overcurrent (OVAD). ADTH is the overcurrent threshold level and is the value set by SPI. Figure 13 shows the curve of detection level. ALFB is divided by 2. Compare this value with ADTH. In recommended application, the zero-point adjustment is required as large error offset in initial condition.

**Figure 13. Motor Current-Sense Block Diagram**

Feature Description (continued)

7.2.7 Regulators

The regulator block offers 3.3-V LDOs. The VCC LDO regulates VB down to 3.3 V with an external PNP controlled by the regulator block. This 3.3-V LDO is supplied to MCU and other components.

The VDD regulator regulates VB down to 3.3 V with internal FET and controller. The 3.3-V LDO with the external PNP is protected against short to GND fault. Overvoltage and undervoltage events of both supplies are detected. The under voltage of the 3.3-V LDO with the external PNP is set by SPI.

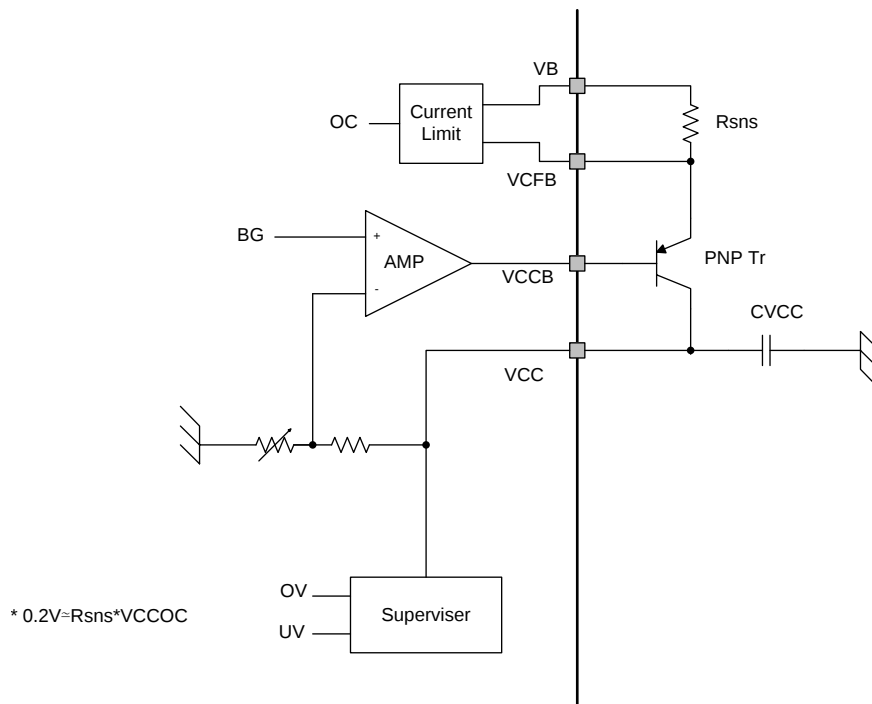


Figure 14. VCC Block Diagram (External Driver)

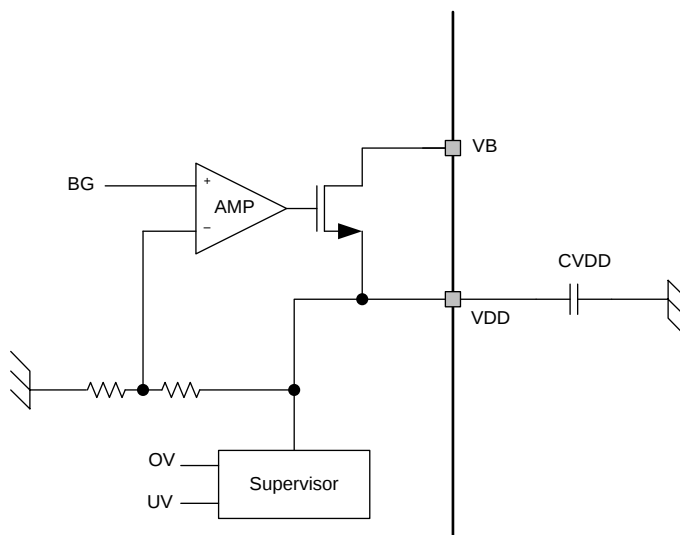


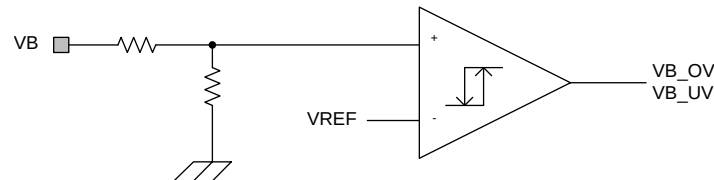
Figure 15. VDD Block Diagram

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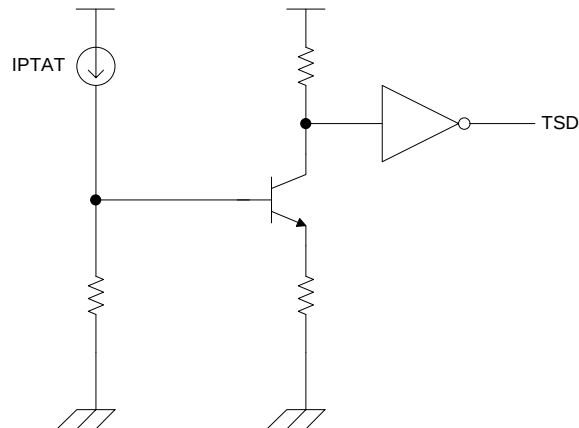
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www.ti.com**Feature Description (continued)****7.2.8 VB Monitor**

The VB monitoring system has two comparators for under- and overvoltage, and has pre-driver stop-controlling system. Overvoltage provides a selectable pre-driver stop condition (SPI control), while undervoltage must stop pre-driver operation under detection (no selectable). The system should return to normal operation automatically after undetected level.

**Figure 16. VB Monitor Block Diagram****7.2.9 Thermal Shutdown**

The device has temperature sensors that produce pre-driver stop condition if the chip temperature exceeds 175°C.

**Figure 17. Thermal Shutdown Block Diagram**

Feature Description (continued)

7.2.10 Oscillator

The oscillator block generates two 10-MHZ clock signals. OSC1 is the primary clock used for internal logic-synchronization and timing control. OSC2 is the secondary clock used to monitor the status of OSC1.

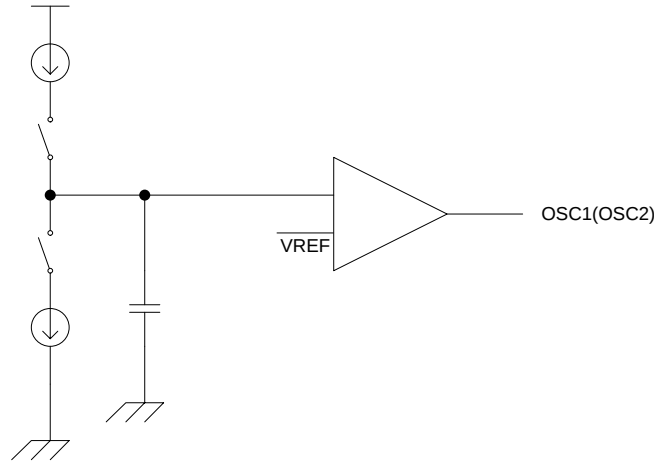
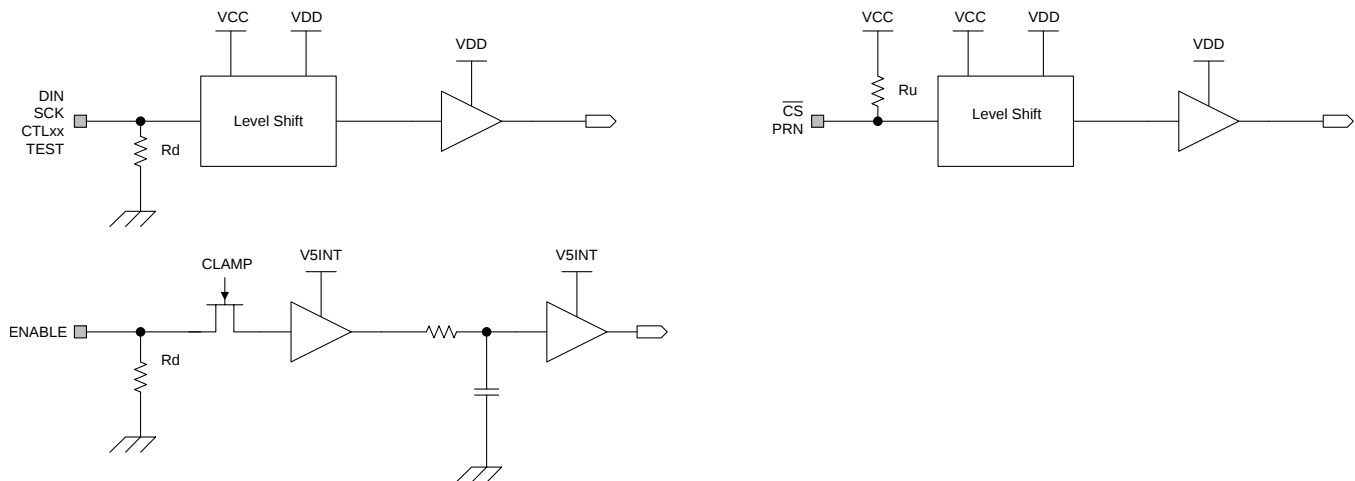


Figure 18. Oscillator Block Diagram

7.2.11 I/O



* V5INT is the internal power supply.

Figure 19. Input Buffer1 Block Diagram

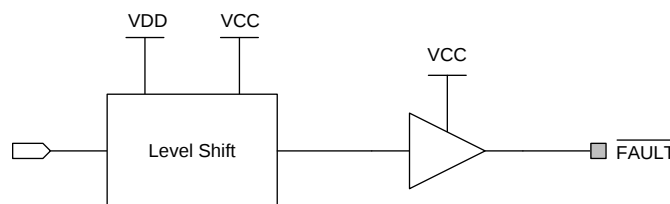
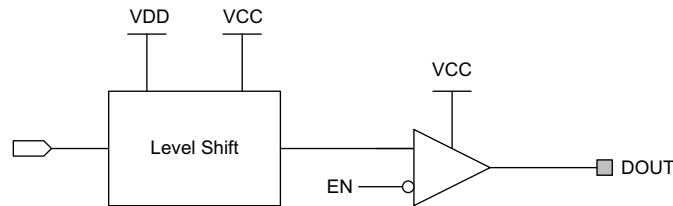
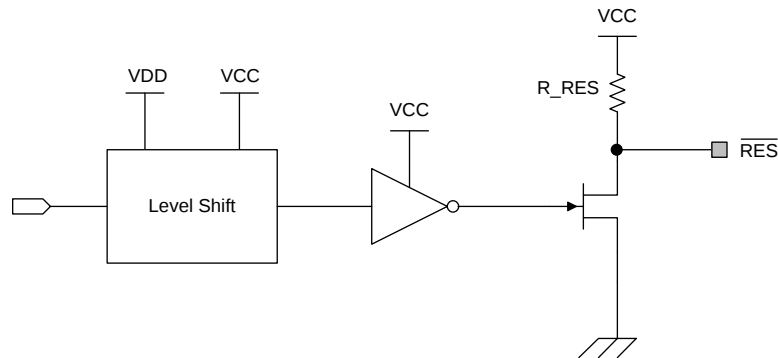


Figure 20. Output Buffer1 Block Diagram

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Feature Description (continued)**Figure 21. Output Buffer2 Block Diagram****Figure 22. Output Buffer3 Block Diagram****Table 1. Recommended Pin Termination**

PIN NAME	DESCRIPTION	TERMINATION
TEST	Test mode input	OPEN

7.2.12 Fault Detection**Table 2. Fault Detection**

ITEMS	SPI FLTLFG	Pre Driver ⁽¹⁾	FAULT ⁽²⁾	RES	Others
VB - Overvoltage	VBOV	Disable	L	H	
VB - Undervoltage	VBUV	Disable	L	H	
CP - Overvoltage	CPOV	Disable	L	H	
CP - Undervoltage	CPUV	Disable	L	H	
VCC - Overvoltage	VCCOV	Disable	L	H	
VCC - Under Voltage	-	Disable ⁽³⁾	H	L	
VCC - Overcurrent	VCCOC	Disable	L	H	
Motor - Overcurrent	MTOC	Disable	L	H	
VDD - Overvoltage	VDDOV	Disable	L	H	
VDD - Undervoltage	-	Disable ⁽³⁾	H	L	
Thermal shutdown	TSD	Disable	L	H	
Watch Dog	-	-	H	L	
Clock Monitor	-	-	H	L	
SPI format error	-	-	H	H	SPI serial out error bit

(1) Pre-driver is disabled if the conditions occur and SDNEN register bits are 1.

(2) FAULT pin is asserted to low if the conditions occur and FLTEN register bits are 1.

(3) Pre-driver is disabled by VCC undervoltage and VDD undervoltage conditions regardless of SPI register setting.

7.3 Register Maps

Table 3. SPI Serial Input Format

	MSB	D14	D13	D12	D11	D10	D9	D8
DIN	RW[1]	RW[0]	Addr[5]	Addr[4]	Addr[3]	Addr[2]	Addr[1]	Addr[0]
	D7	D6	D5	D4	D3	D2	D1	LSB
DIN	Data[7]	Data[6]	Data[5]	Data[4]	Data[3]	Data[2]	Data[1]	Data[0]

Table 4. SPI Serial Output Data Format

	MSB	D14	D13	D12	D11	D10	D9	D8
DOUT	0	Frame fault	0	0	0	0	0	1
	D7	D6	D5	D4	D3	D2	D1	LSB
DOUT	Data[7]	Data[6]	Data[5]	Data[4]	Data[3]	Data[2]	Data[1]	Data[0]

SPI serial input and output format

RW[1:0] : 01: write mode; 00: read mode

Addr[5:0] : Address of SPI access

Data[7:0] : Input data to write or output data to read

Frame fault : 0: No error exists in the previous SPI frame.

: 1: Error exists in the previous SPI frame.

Table 5. SPI Register Map

Register Name	Addr (Hex)	b7	b6	b5	b4	b3	b2	b1	b0	Reset (Hex)
Reserved	00	RSVD								00
CFGUNLK	01	RSVD				CFGUNLK				00
FLTCFG	02	FLGLATCH_EN	MTOCTH			RSVD	VCCUVTH	VBUVTH		00
Reserved	03	RSVD								00
FLTEN0	04	FE_MTOC	FE_VCCOC	FE_VCCOV	FE_VDDOV	FE_CPOV	FE_CPUV	FE_VBOV	FE_VBUV	FF
FLTEN1	05	RSVD							FE_TSD	01
SDNEN0	06	SE_MTOC	SE_VCCOC	SE_VCCOV	SE_VDDOV	SE_CPOV	SE_CPUV	SE_VBOV	SE_VBUV	FF
SDNEN1	07	RSVD							SE_TSD	01
FLTFLG0	08	MTOC	VCCOC	VCCOV	VDDOV	CPOV	CPUV	VBOV	VBUV	00
FLTFLG1	09	RSVD							TSD	00
CSCFG	0A	RSVD				CSOFFSET				00
PDCFG	0B	RSVD					DEADT			00
DIAG	0C	RSVD				VCCUVRST	WDTRST	CMRST	00	
SPARE	0D	SPARE						SEL_COMP_HYS		00
Reserved	0E-3F	RSVD								00

7.3.1 Register Descriptions

Access type: R = Read and W = Write.

Reserved register: Read of reserved bits return 0 and write has no effect.

7.3.1.1 CFGUNLK (address 0x01): Configuration Unlock Register

Bit	Name	Type	Reset	Description
3:0	CFGUNLK	RW	0000	DRV3203E-Q1 SPI register map has lock and unlock mode, and it is in lock mode by default. MCU can write values of the following registers in unlock mode; • FLTCFG • FLTEN0 and FLTEN1 • SDNEN0 and SDNEN1 • CSCFG

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Bit	Name	Type	Reset	Description
				• PDCFG • WDCFG In lock mode, read returns the values, but writing the registers have no effect. Device enters unlock mode by writing 0x5, 0x8, 0x7 to CFGUNLK register in series. Device exits from unlock mode by writing 0x0.

7.3.1.2 FLTCFG (address 0x02): Fault Detection Configuration Register

Bit	Name	Type	Reset	Description
7	FLGLATCH_EN	RW	0	Fault-flag (FLTFLG*) latch enable 0: Fault events do not latch fault-flag register bits. 1: Latching of fault-flag register bits by the fault events occurs. The flag bits remain asserted until cleared.
6:4	MTOCTH	RW	000	Motor overcurrent detection threshold (ADTH) 000: 1.32 V 001: 1.65 V 010: 1.98 V 011: 2.31 V 100: 2.64 V Others: 1.32 V
3	RSVD	R	0	Reserved
2	VCCUVTH	RW	0	VCC undervoltage detection threshold 0: 2.2 V 1: 2.4 V
1:0	VBUVTH	RW	00	VB undervoltage detection threshold 00: 4 V 01: 4.5 V 10: 5 V 11: 5.5 V

7.3.1.3 FLTEN0 (address 0x04): FAULT Pin Enable Register 0

Bit	Name	Type	Reset	Description
7	FE_MTOC	RW	1	FAULT pin enable of FLTFLG0 register bits. 0: Assertion of the FAULT pin does not occur when the fault flag bit is 1 1: Assertion of the FAULT pin to low level occurs when the fault flag bit is 1. See Figure 23
6	FE_VCCOC	RW	1	
5	FE_VCCOV	RW	1	
4	FE_VDDOV	RW	1	
3	FE_CPOV	RW	1	
2	FE_CPUV	RW	1	
1	FE_VBOV	RW	1	
0	FE_VBUV	RW	1	

7.3.1.4 FLTEN1 (address 0x05): FAULT Pin Enable Register 1

Bit	Name	Type	Reset	Description
7:1	RSVD	R	0000 000	Reserved
0	FE_TSD	RW	1	FAULT pin enable of TSD flag bit 0: Assertion of the FAULT pin does not occur when the fault flag bit is 1 1: Assertion of the FAULT pin to low level occurs when the TSD flag bit is 1. See Figure 23

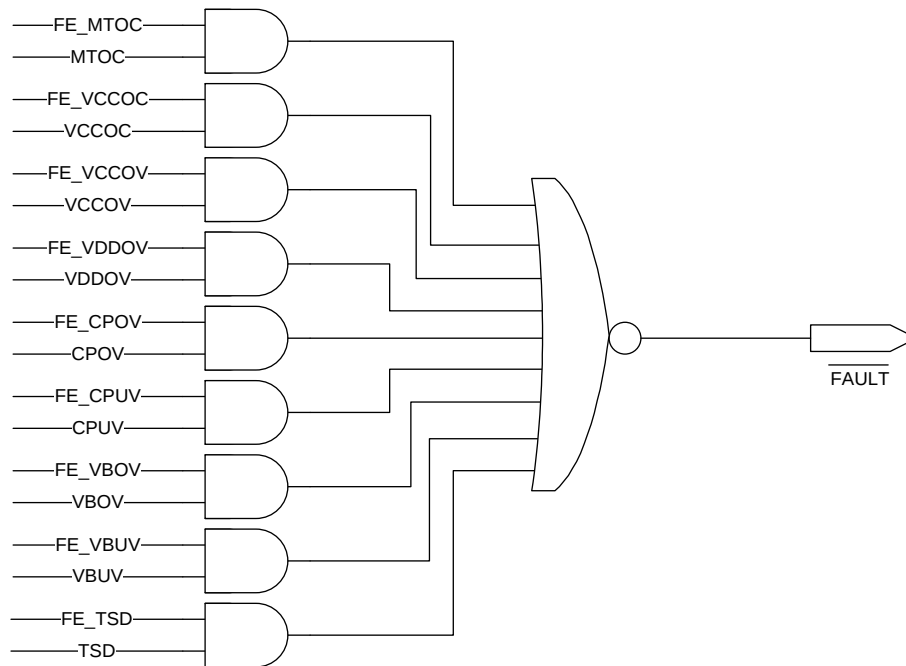


Figure 23. FAULT Pin Enable Logic

7.3.1.5 SDNEN0 (address 0x06): Pre-Driver Shutdown Enable Register 0

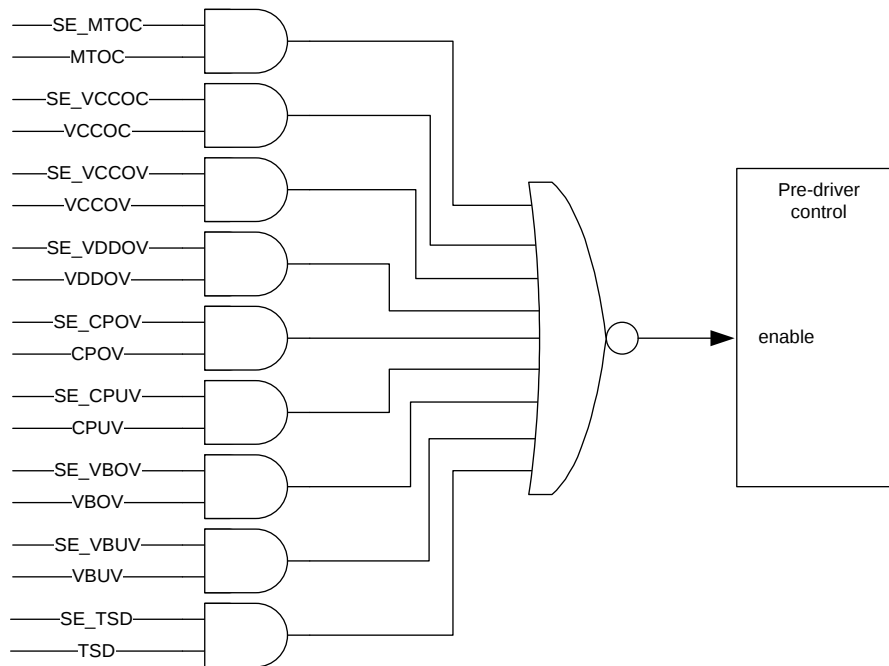
Bit	Name	Type	Reset	Description
7	SE_MTOC	RW	1	Pre-driver shutdown enable of FLTFLG0 register bits 0: Disabling of the pre-driver outputs does not occur when the fault flag bit is 1. 1: Disabling of the pre-driver outputs occurs when the fault flag bit is 1. Both the high-side and low-side FETs turn off. See Figure 24 .
6	SE_VCCOC	RW	1	
5	SE_VCCOV	RW	1	
4	SE_VDDOV	RW	1	
3	SE_CPOV	RW	1	
2	SE_CPUV	RW	1	
1	SE_VBOV	RW	1	
0	SE_VBUV	RW	1	

7.3.1.6 SDNEN1 (address 0x07): Pre-Driver Shutdown Enable Register 1

Bit	Name	Type	Reset	Description
7:1	RSVD	R	0000 000	Reserved
0	SE_TSD	RW	1	Pre-driver shutdown enable of TSD flag bits 0: Disabling of the pre-driver outputs does not occur when the TSD flag bit is 1. 1: Disabling of the pre-driver outputs occurs when the TSD flag bit is 1. Both the high-side and low-side FETs turn off. See Figure 24 .

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www.ti.com**Figure 24. Pre-Driver Shutdown Logic****7.3.1.7 FLTLG0 (address 0x08): Fault Flag Register 0**

Bit	Name	Type ⁽¹⁾	Reset	Description
				Fault flag bits of the following conditions; ⁽²⁾
7	MTOC	RW	0	MTOC: Motor overcurrent. (OVAD)
6	VCCOC	RW	0	VCCOC: VCC overcurrent
5	VCCOV	RW	0	VCCOV: VCC overvoltage
4	VDDOV	RW	0	VDDOV: VDD overvoltage
3	CPOV	RW	0	CPOV: Charge-pump overvoltage
2	CPUV	RW	0	CPUV: Charge-pump undervoltage
1	VBOV	RW	0	VBOV: VB overvoltage
0	VBUV	RW	0	VBUV: VB undervoltage
				If FLTCFG.FLGLATCH_EN = 1
				0: Read = No fault condition exists since last cleared. Write = No effect
				1: Read = Fault condition exists. Write = Clear the flag.
				If FLTCFG.FLGLATCH_EN = 0
				0: Read = No fault condition Write = No effect
				1: Read = Fault condition Write = No effect

(1) R: Read, W: Write

(2) Assertion of the fault flags may occur during power up.

7.3.1.8 FLGFLT1 (address 0x09): Fault Flag Register 1

Bit	Name	Type ⁽¹⁾	Reset	Description
7:1	RSVD	R	0000 000	Reserved
0	VBUV	RW	1	Fault flag bit of thermal shutdown condition.⁽²⁾ If FLTCFG.FLGLATCH_EN = 1 0: Read = No fault condition exists since last cleared. Write = No effect 1: Read = Fault condition exists. Write = Clear the flag If FLTCFG.FLGLATCH_EN = 0 0: Read = No fault condition Write = No effect 1: Read = Fault condition Write = No effect

(1) R: Read, W: Write

(2) Assertion of the fault flags may occur during power up.

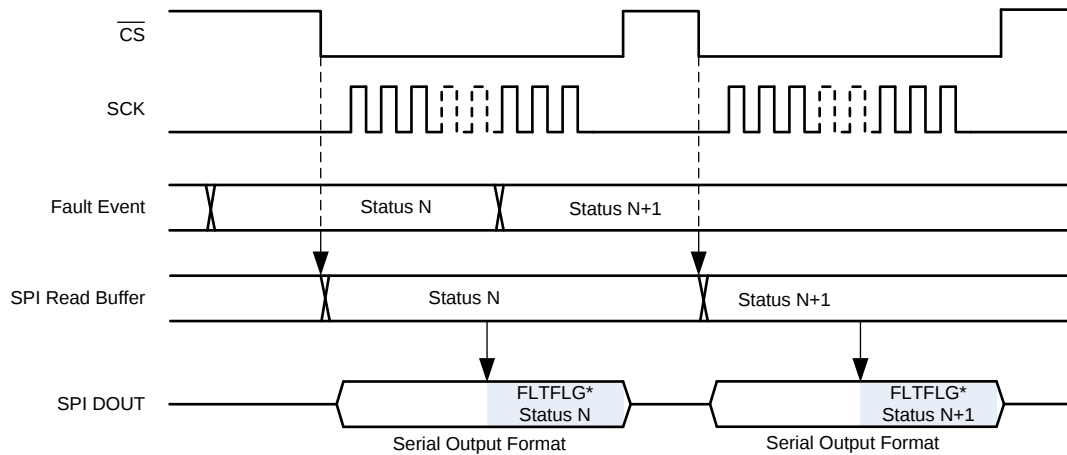
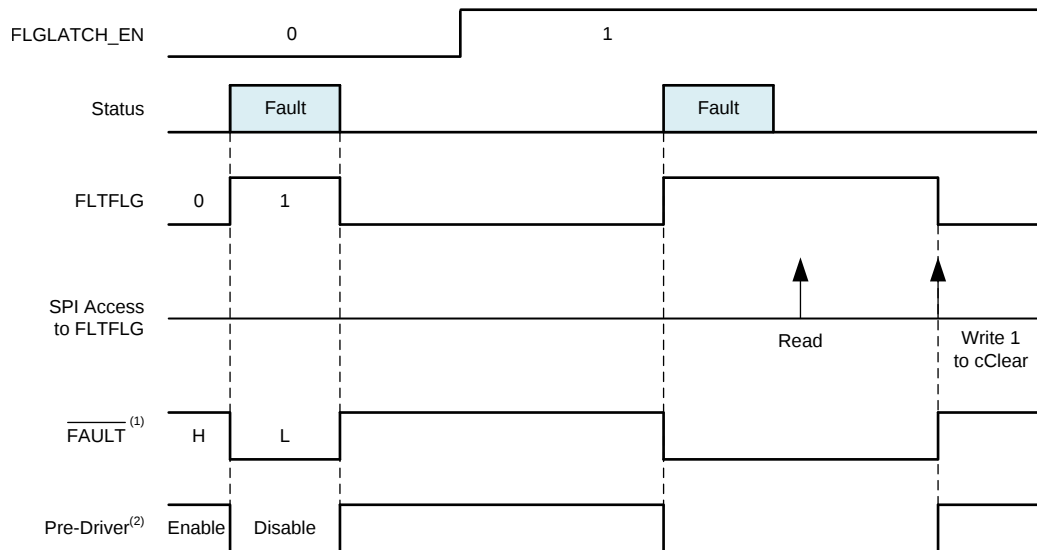


Figure 25. SPI Data-Out Timing Chart of Fault Flag Registers

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(1) Assertion of $\overline{\text{FAULT}}$ occurs if $\text{FLTEN} = 1$.(2) Disabling of pre-driver occurs if $\text{SDNEN} = 1$.**Figure 26. FLGFLG and FLGLATCH_EN****7.3.1.9 CSCFG (address 0x0A): Current Sense Configuration Register**

Bit	Name	Type ⁽¹⁾	Reset	Description
7:3	RSVD	R	0000 0	Reserved
2:0	CSOFFSET	RW	000	Current-sense offset 000: 0.5 V 001: 1 V 010: 1.5 V Others: 0.5 V

(1) R: Read W: Write

7.3.1.10 PDCFG (address 0x0B): Pre-Driver Configuration Register

Bit	Name	Type ⁽¹⁾	Reset	Description
7:2	RSVD	R	0000 00	Reserved
1:0	DEADT	RW	00	Dead time (= t_{dead}) 00: 2.1 μs 01: 1.6 μs 10: 1.1 μs 11: 0.6 μs The actual dead time has $\pm 0.1\text{-}\mu\text{s}$ variation from the typical value.

(1) R: Read W: Write

7.3.1.11 DIAG (address 0x0C): Diagnosis Register

Bit	Name	Type	Reset	Description
7:3	RSVD	R	0000 0	Reserved
2	VCCUVRST	R	0	nRES reset source information Bit 2 = VCCUVRST - VCC undervoltage Bit 1 = WDTRST - watchdog timer Bit 0 = CMRST - clock monitor 0: Read = Reset has not occurred.
1	WDTRST	R	0	
0	CMRST	R	0	

Bit	Name	Type	Reset	Description
				Write = No effect 1: Read = A corresponding reset source caused the last reset condition. Write = No effect Read access to this register clears the bits.

7.3.1.12 SPARE (address 0x0D): Spare Register

Bit	Name	Type ⁽¹⁾	Reset	Description
7:2	SPARE	RW	0000 00	Spare registers for future use. Read and write have no effect.
1:0	SEL_COMP_HYS	RW	00	Select phase comparator hysteresis voltage. The following show the typical values. 00: 0 V 01: 25 mV 10: 50 mV 11: 100 mV

(1) R: Read W: Write

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

[illegible]

Product Folder Links: [DRV3203E-Q1](#)

9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

9.3 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

9.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV3203EPHPRQ1	Obsolete	Production	HTQFP (PHP) 48	-	-	Call TI	Call TI	-	DRV3203E

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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GENERIC PACKAGE VIEW

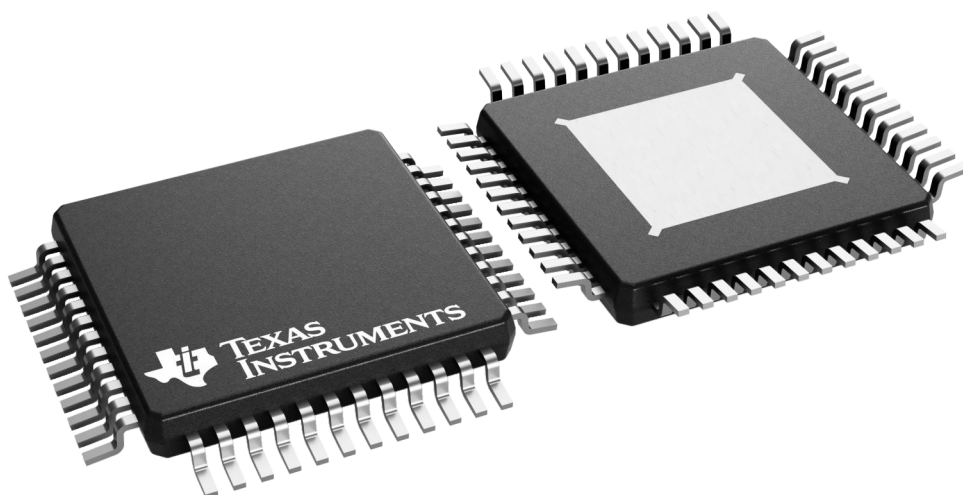
PHP 48

TQFP - 1.2 mm max height

7 x 7, 0.5 mm pitch

QUAD FLATPACK

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



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